







OPA1688 36-V, Single-Supply, 10-MHz, Rail-to-Rail Output, SoundPlus™ Audio Operational Amplifier

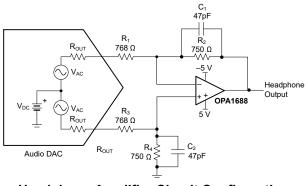


1 Features

- THD+N, 50 mW, 32 Ω, 1 kHz, –109 dB
- Wide supply range:
 - 4.5 V to 36 V, ±2.25 V to ±18 V
- Low offset voltage: ±0.25 mV
- Low offset drift: ±0.5 µV/°C
- Gain bandwidth: 10 MHz
- Low input bias current: ±10 pA
- Low quiescent current: 1.6 mA per amplifier
- Low noise: 8 nV/√Hz
- EMI- and RFI-filtered inputs
- · Input range includes negative supply
- Input range operates to positive supply
- Rail-to-rail output
- High common-mode rejection: 120 dB
- Packages:
 - Industry-standard SOIC-8
 - micro WSON-8

2 Applications

- Professional microphones and wireless systems
- Professional audio mixer and control surface
- Guitar amp and other music instrument amps
- A/V receiver
- Bookshelf stereo system
- Professional audio amplifier (rack mount)
- DJ equipment
- Turntable
- Special function module



Headphone Amplifier Circuit Configuration

3 Description

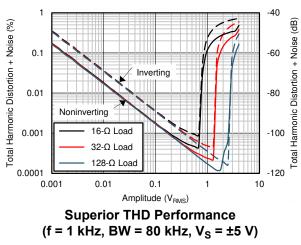
OPA1688 The 36-V. single-supply, low-noise SoundPlus[™] audio operational amplifier is capable of operating on supplies ranging from 4.5 V (±2.25 V) to 36 V (±18 V). This latest addition of a high-voltage audio operational amplifier in conjunction with the OPA16xx devices provide a family of bandwidth, noise, and power options to meet the needs of a wide variety of applications. The OPA1688 is available in a WSON micropackage, and offers low offset, drift, and quiescent current. This device also offers wide bandwidth, fast slew rate, and high output current drive capability.

Unlike most op amps that are specified at only one supply voltage, the OPA1688 is specified from 4.5 V to 36 V. Input signals beyond the supply rails do not cause phase reversal. The input can operate 100 mV below the negative rail and within 2 V of the top rail during normal operation. Note that this device can operate with full rail-to-rail input 100 mV beyond the top rail, but with reduced performance within 2 V of the top rail.

The OPA1688 is specified from -40°C to +85°C.

Device Information					
PART NUMBER PACKAGE ⁽¹⁾ BODY SIZE (NO					
OPA1688	SOIC (8)	4.90 mm × 3.91 mm			
	WSON (8)	3.00 mm × 3.00 mm			

 For all available packages, see the orderable addendum at the end of the data sheet.



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision * (September 2015) to Revision A (June 2022)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Added operating temperature to Recommended Operating Conditions table; moved from Electrical	
	Characteristics table	4
•	Deleted redundant power supply row from <i>Electrical Characteristics</i> table; content already listed in	
	Recommended Operating Conditions table	5
•	Deleted redundant specified temperature row from Electrical Characteristics table; content already liste	d in
	Recommended Operating Conditions table	5
•	Deleted operating temperature row from Electrical Characteristics table; moved content to Recommend	ded
	Operating Conditions table	<mark>5</mark>



5 Device Comparison Table

DEVICE	QUIESCENT CURRENT (I _Q)	GAIN BANDWIDTH PRODUCT (GBP)	VOLTAGE NOISE DENSITY (e _n)
OPA1688	1650 µA	10 MHz	8 nV/√Hz
OPA165x	2000 µA	18 MHz	4.5 nV/√Hz
OPA166x	1500 µA	22 MHz	3.3 nV/√Hz

6 Pin Configuration and Functions

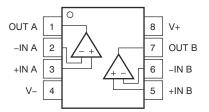


Figure 6-1. D (SOIC-8) Package, Top View

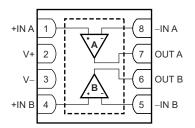


Figure 6-2. DRG (WSON-8) Package, Top View

PIN I				
	N	0.		
NAME	D (SOIC)	DRG (WSON)	TYPE	DESCRIPTION
–IN A	2	8	Input	Inverting input, channel A
–IN B	6	5	Input	Inverting input, channel B
+IN A	3	1	Input	Noninverting input, channel A
+IN B	5	4	Input	Noninverting input, channel B
OUT A	1	7	Output	Output, channel A
OUT B	7	6	Output	Output, channel B
V–	4	3	Power	Negative (lowest) power supply
V+	8	2	Power	Positive (highest) power supply

Table 6-1. Pin Functions



7 Specifications

7.1 Absolute Maximum Ratings

over operating free	-air temperature	range (unless	otherwise noted) ⁽¹⁾

			MIN	MAX	UNIT	
Supply voltage, V _S				±20 (40, single supply)	V	
	λ (alta α (2)	Common-mode	(V–) – 0.5	(V+) + 0.5	V	
Signal input pins	Voltage ⁽²⁾	Differential ⁽⁴⁾		±0.5	V	
	Current			±10	mA	
Output short circuit ⁽³⁾			Continuous			
	Temperature range	9	-55	150	°C	
Temperature	Junction temperate	ure		150	°C	
	Storage, T _{stg}		-65	150	°C	

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Transient conditions that exceed these voltage ratings should be current limited to 10 mA or less.

(3) Short-circuit to ground, one amplifier per package.

(4) See Section 8.4.2 section for more information.

7.2 ESD Ratings

				VALUE	UNIT
V		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	V	
V((ESD)		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	v

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM MAX	UNIT
Supply voltage, V _S (V+ – V–)	4.5 (±2.25)	36 (±18)	V
Specified temperature	-40	85	°C
Operating temperature	-55	125	°C

7.4 Thermal Information

		OPA		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DRG (WSON)	UNIT
		8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	116.1	63.2	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	69.8	63.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	56.6	36.5	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	22.5	1.4	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	56.1	36.6	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	6.3	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



7.5 Electrical Characteristics

at $T_A = 25^{\circ}$ C, $V_S = \pm 2.25$ V to ± 18 V, $V_{CM} = V_{OUT} = V_S / 2$, and $R_L = 10$ k Ω connected to $V_S / 2$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
AUDIO PE	RFORMANCE					
				0.00005%		
		G = 1, f = 1 kHz, V_0 = 3.5 V_{RMS} , R_L = 2 k Ω		-126		dB
				0.000051%		
		G = 1, f = 1 kHz, V_0 = 3.5 V_{RMS} , R_L = 600 Ω		-126		dB
	Total harmonia distartian			0.000153%		
THD+N	Total harmonic distortion + noise	$G = 1, f = 1 \text{ kHz}, P_O = 10 \text{ mW}, R_L = 128 \Omega$		-116		dB
				0.000357%		dD
		G = 1, f = 1 kHz, P_O = 10 mW, R_L = 32 Ω		-109		dB
						uВ
		G = 1, f = 1 kHz, P_O = 10 mW, R_L = 16 Ω		0.000616%		
				-104		dB
GBP	Gain bandwidth product	G = 1		10		MHz
SR	Slew rate	G = 1		8		V/µs
	Full-power bandwidth ⁽¹⁾	V _O = 1 V _{PP}		1.3		MHz
	Overload recovery time	V _{IN} × gain > V _S		200		ns
	Channel separation (dual)	f = 1 kHz		-120		dB
t _S	Settling time	To 0.1%, V _S = ±18 V, G = 1, 10-V step		3		μs
NOISE		1				
En	Input voltage noise	f = 0.1 Hz to 10 Hz		2.5		μV _{PP}
	Input voltage noise	f = 100 Hz		14		
e _n	density ⁽²⁾	f = 1 kHz		8		nV/√Hz
i _n	Input current noise density	f = 1 kHz		1.8		fA/√Hz
OFFSET V	-					
		T _A = 25°C		±0.25	±1.5	
V _{OS}	Input offset voltage	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			±1.6	mV
dV _{OS} /dT	V _{OS} over temperature ⁽²⁾	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$		±0.5	±2	μV/°C
PSRR	Power-supply rejection ratio	$T_A = -40^{\circ}$ C to +85°C		±1	±2.5	μν/ σ
		At dc		0.1		
	Channel separation, dc	Alde		0.1		μV/V
	AS CURRENT	T 0500		. 40		•
I _B	Input bias current	T _A = 25°C		±10	±20	pA
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			±1.5	nA
los	Input offset current	T _A = 25°C		±3	±7	pА
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$			±250	pА
INPUT VO	LTAGE RANGE	1	1			
V _{CM}	Common-mode voltage range ⁽³⁾		(V–) – 0.1 V		(V+) – 2 V	V
	Common-mode rejection ratio	$V_{S} = \pm 2.25 \text{ V}, (V_{-}) - 0.1 \text{ V} < V_{CM} < (V_{+}) - 2 \text{ V},$ $T_{A} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$	90	104		40
CMRR		$V_{S} = \pm 18 V$, (V-) - 0.1 V < V _{CM} < (V+) - 2 V, T _A = -40°C to +85°C	104	120		dB
	PEDANCE	1	1			
	Differential			100 7		MΩ pF
	Common-mode			6 1.5		10 ¹² Ω pF



7.5 Electrical Characteristics (continued)

at $T_A = 25^{\circ}$ C, $V_S = \pm 2.25$ V to ± 18 V, $V_{CM} = V_{OUT} = V_S / 2$, and $R_L = 10$ k Ω connected to $V_S / 2$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OPEN-LO	DOP GAIN					
A _{OL} Open-lo		$(V-) + 0.35 V < V_O < (V+) - 0.35 V$, $R_L = 10 k\Omega$, $T_A = -40^{\circ}C$ to +85°C	108	130		dB
AOL	Open-loop voltage gain	$(V-) + 0.5 V < V_O < (V+) - 0.5 V, R_L = 2 k\Omega, T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		118		
OUTPUT	•					
	Voltage output swing	$I_L = \pm 1 \text{ mA}$	(V–) + 0.1 V		(V+) – 0.1 V	
Vo		$V_{\rm S}$ = 36 V, R _L = 10 k Ω		70	90	mV
		$V_{\rm S}$ = 36 V, R _L = 2 k Ω		330	400	
Zo	Open-loop output impedance	f = 1 MHz, I _O = 0 A		60		Ω
I _{SC}	Short-circuit current			±75		mA
C _{LOAD}	Capacitive load drive		See	Section 7.6		pF
POWER	SUPPLY		L		I.	
	Quiescent current per	I _O = 0 A		1.6	1.8	
lQ	amplifier				2	mA

Full-power bandwidth = SR / $(2\pi \times V_P)$, where SR = slew rate. (1)

(2) (3) Specified by design and characterization.

Common-mode range can extend to the top rail with reduced performance.



7.6 Typical Characteristics

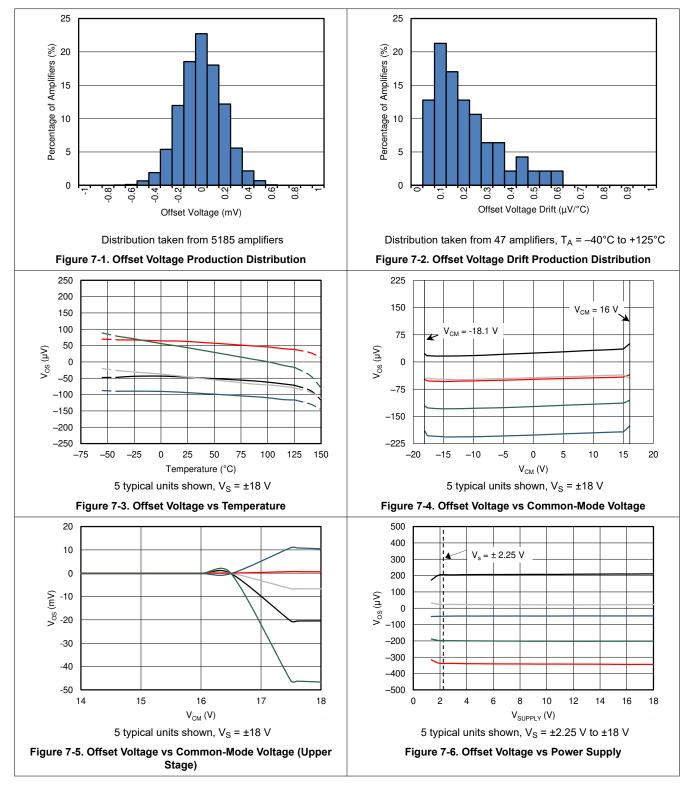
at V_S = ±18 V, V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 100 pF (unless otherwise noted)

Table 7-1. List of Typical Characteristics

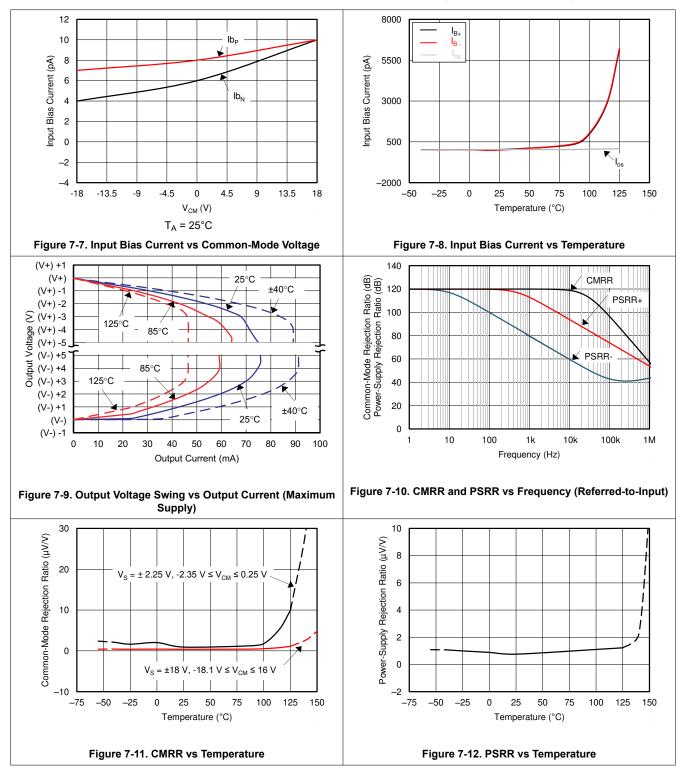
DESCRIPTION	FIGURE
Offset Voltage Production Distribution	Figure 7-1
Offset Voltage Drift Distribution	Figure 7-2
Offset Voltage vs Temperature (V _S = ±18 V)	Figure 7-3
Offset Voltage vs Common-Mode Voltage (V _S = ±18 V)	Figure 7-4
Offset Voltage vs Common-Mode Voltage (Upper Stage)	Figure 7-5
Offset Voltage vs Power Supply	Figure 7-6
Input Bias Current vs Common-Mode Voltage	Figure 7-7
Input Bias Current vs Temperature	Figure 7-8
Output Voltage Swing vs Output Current (Maximum Supply)	Figure 7-9
CMRR and PSRR vs Frequency (Referred-to-Input)	Figure 7-10
CMRR vs Temperature	Figure 7-11
PSRR vs Temperature	Figure 7-12
0.1-Hz to 10-Hz Noise	Figure 7-13
Input Voltage Noise Spectral Density vs Frequency	Figure 7-14
THD+N Ratio vs Frequency	Figure 7-15
THD+N vs Output Amplitude	Figure 7-16
THD+N vs Frequency	Figure 7-17
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Quiescent Current vs Temperature	Figure 7-19
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Positive Overload Recovery	Figure 7-27, Figure 7-28
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Small-Signal Step Response (10 mV, G = 1)	Figure 7-32
Small-Signal Step Response (100 mV, G = -1)	Figure 7-33
Small-Signal Step Response (100 mV, G = 1)	Figure 7-34
Large-Signal Step Response (10 V, G = -1)	Figure 7-35
Large-Signal Step Response (10 V, G = 1)	Figure 7-36
Large-Signal Settling Time (10-V Positive Step)	Figure 7-37
Large-Signal Settling Time (10-V Negative Step)	Figure 7-38
No Phase Reversal	Figure 7-39
Short-Circuit Current vs Temperature	Figure 7-40
Maximum Output Voltage vs Frequency	Figure 7-41
EMIRR vs Frequency	Figure 7-42
Channel Separation vs Frequency	Figure 7-43



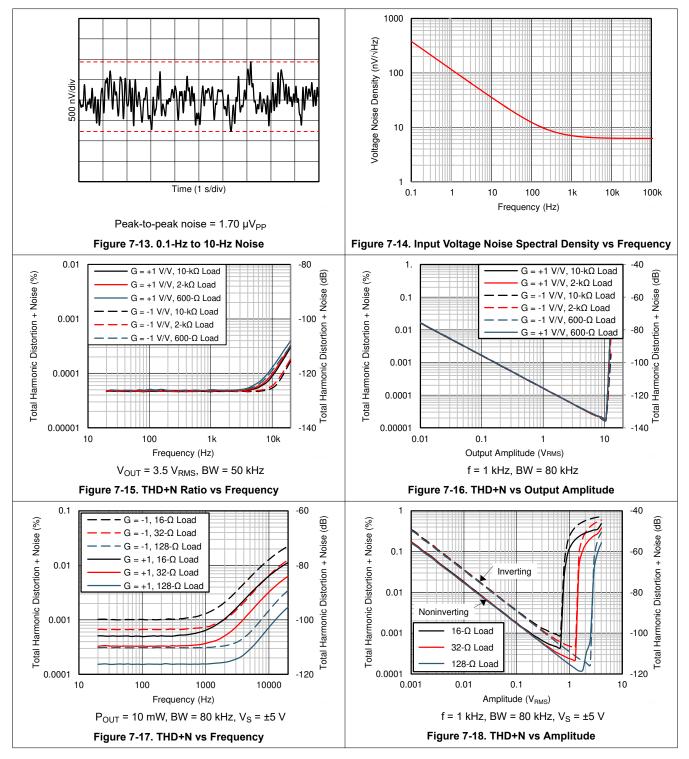
7.6 Typical Characteristics



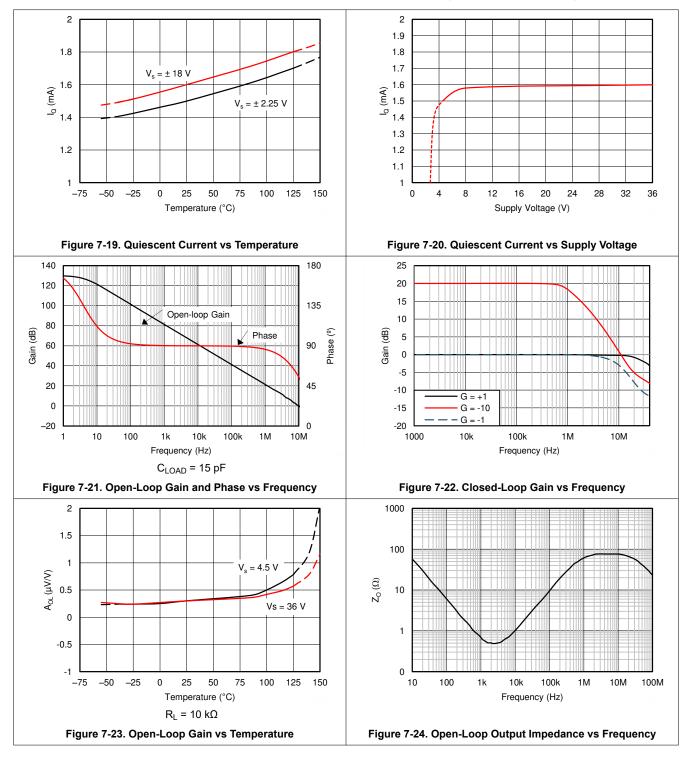




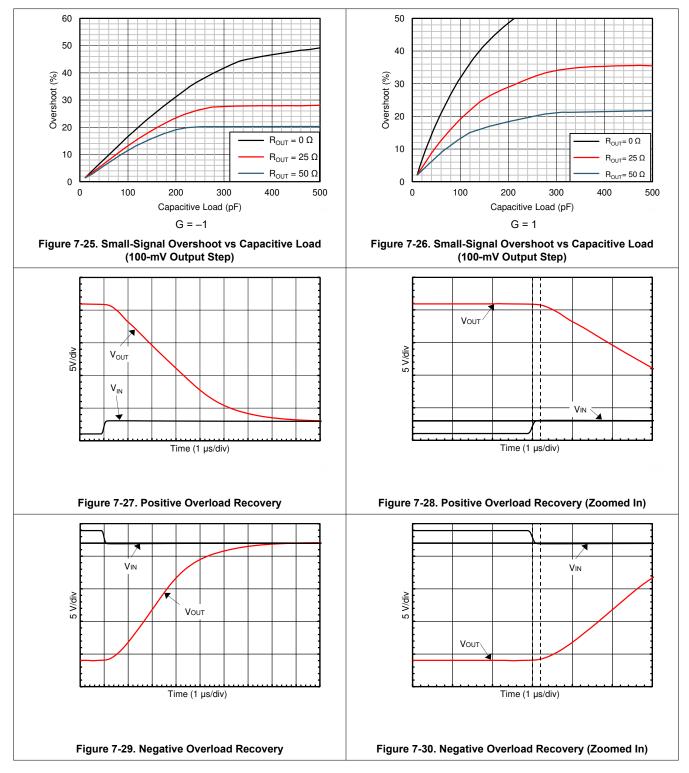




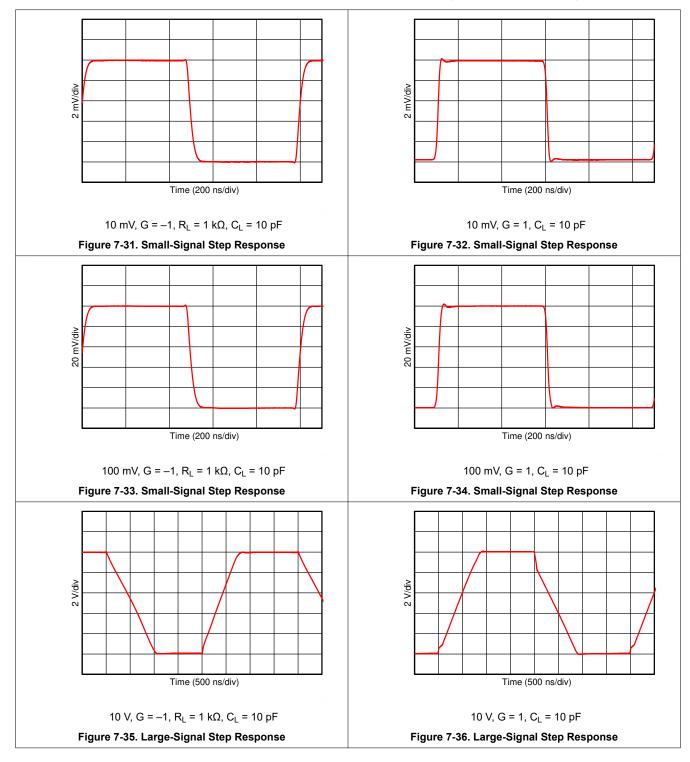




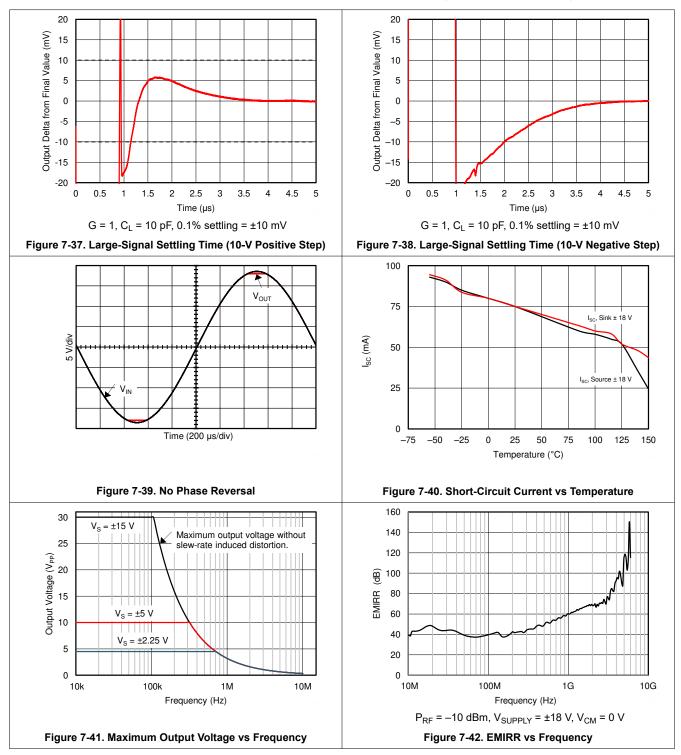




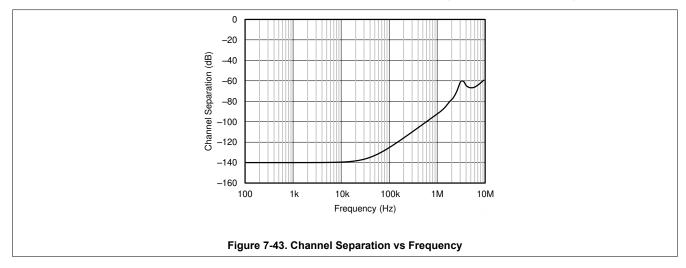














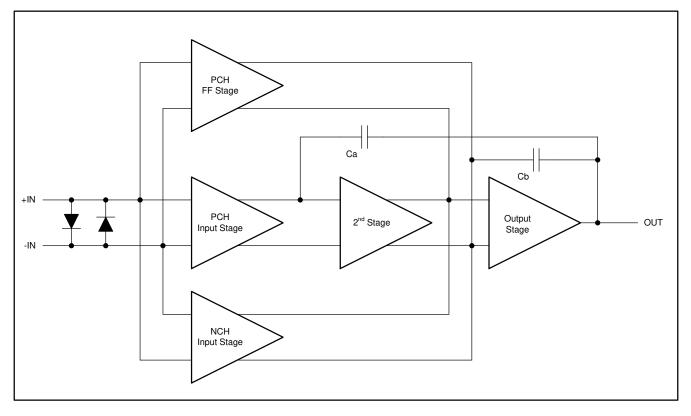
8 Detailed Description

8.1 Overview

The OPA1688 op amp provides high overall performance, making the device an excellent choice for many general-purpose applications. The excellent offset drift of only 1.5 μ V/°C (max) provides excellent stability over the entire temperature range. In addition, the device offers very good overall performance with high CMRR, PSRR, A_{OL}, and superior THD.

Section 8.2 shows the simplified diagram of the OPA1688 design. The design topology is a highly-optimized, three-stage amplifier with an active-feedforward gain stage.

8.2 Functional Block Diagram

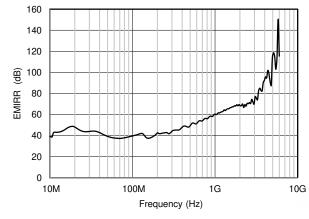




8.3 Feature Description

8.3.1 EMI Rejection

The OPA1688 uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources such as wireless communications and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the OPA1688 benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. Figure 8-1 shows the results of this testing on the OPA1688. Table 8-1 shows the EMIRR IN+ values for the OPA1688 at particular frequencies commonly encountered in real-world applications. Applications listed in Table 8-1 can be centered on or operated near the particular frequency shown. Detailed information can also be found in the *EMI Rejection Ratio of Operational Amplifiers* application report, available for download from www.ti.com.



 $P_{RF} = -10 \text{ dBm}, V_{SUPPLY} = \pm 18 \text{ V}, V_{CM} = 0 \text{ V}$

Figure 8-1. EMIRR Testing

Table 8-1. OPA1688 EMIRR IN+ for Frequencies of Interest

FREQUENCY	APPLICATION OR ALLOCATION	EMIRR IN+				
400 MHz	Mobile radio, mobile satellite, space operation, weather, radar, and ultrahigh frequency (UHF) applications	47.6 dB				
900 MHz	Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, and UHF applications	58.5 dB				
1.8 GHz	GSM applications, mobile personal communications, broadband, satellite, and L-band (1 GHz to 2 GHz)	68 dB				
2.4 GHz	802.11b, 802.11g, 802.11n, Bluetooth [®] , mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, and S-band (2 GHz to 4 GHz)	69.2 dB				
3.6 GHz	Radiolocation, aero communication and navigation, satellite, mobile, and S-band	82.9 dB				
5.0 GHz	5.0 GHz 802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, and C-band (4 GHz to 8 GHz)					



8.3.2 Phase-Reversal Protection

The OPA1688 has internal phase-reversal protection. Many op amps exhibit phase reversal when the input is driven beyond the linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input of the OPA1688 prevents phase reversal with excessive common-mode voltage. Instead, the appropriate rail limits the output voltage. Figure 8-2 shows this performance.

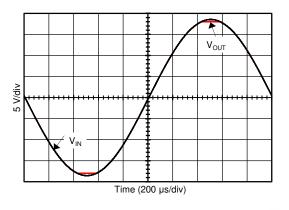
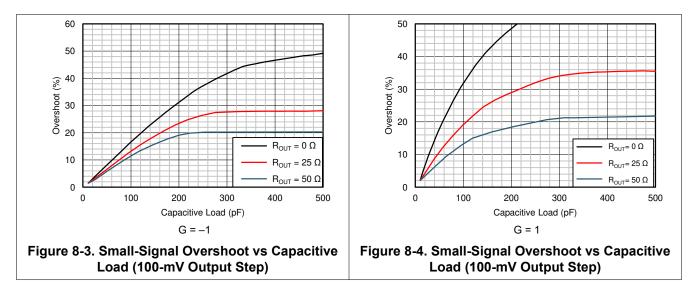


Figure 8-2. No Phase Reversal

8.3.3 Capacitive Load and Stability

The dynamic characteristics of the OPA1688 are optimized for commonly-used operating conditions. The combination of low closed-loop gain and high capacitive loads decreases the phase margin of the amplifier and may lead to gain peaking or oscillations. As a result, heavier capacitive loads must be isolated from the output. The simplest way to achieve this isolation is to add a small resistor (for example, $R_{OUT} = 50 \Omega$) in series with the output. Figure 8-3 and Figure 8-4 show graphs of small-signal overshoot versus capacitive load for several values of R_{OUT} ; see the *Feedback Plots Define Op Amp AC Performance* application bulletin, available for download from www.ti.com, for details of analysis techniques and application circuits.





8.4 Device Functional Modes

8.4.1 Common-Mode Voltage Range

The input common-mode voltage range of the OPA1688 extends 100 mV below the negative rail and within 2 V of the top rail for normal operation.

This device can operate with full rail-to-rail input 100 mV beyond the top rail, but with reduced performance within 2 V of the top rail. Table 8-2 summarizes the typical performance in this range.

Table 8-2. Typical Performance Range (V _S = ±18 V)										
PARAMETER	MIN	TYP	MAX	UNIT						
Input common-mode voltage	(V+) − 2		(V+) + 0.1	V						
Offset voltage		5		mV						
Offset voltage vs temperature ($T_A = -40^{\circ}C$ to $85^{\circ}C$)		10		µV/°C						
Common-mode rejection		70		dB						
Open-loop gain		60		dB						
Gain bandwidth product (GBP)		4		MHz						
Slew rate		4		V/µs						
Noise at f = 1 kHz		22		nV/√Hz						

8.4.2 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress. These questions tend to focus on the device inputs, but can involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

A good understanding of this basic ESD circuitry and its relevance to an electrical overstress event is helpful. Figure 8-5 illustrates the ESD circuits contained in the OPA1688 (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where the diodes meet at an absorption device internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.

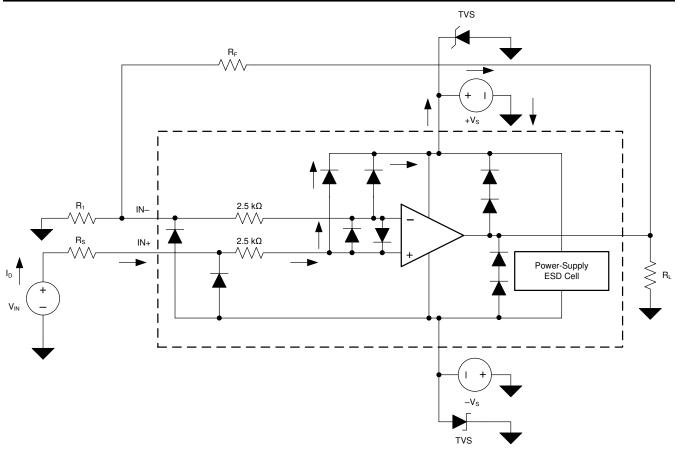


Figure 8-5. Equivalent Internal ESD Circuitry Relative to a Typical Circuit Application

An ESD event produces a short-duration, high-voltage pulse that is transformed into a short-duration, highcurrent pulse when discharging through a semiconductor device. The ESD protection circuits are designed to provide a current path around the operational amplifier core to prevent damage. The energy absorbed by the protection circuitry is then dissipated as heat.

When an ESD voltage develops across two or more amplifier device pins, current flows through one or more steering diodes. Depending on the path that the current takes, the absorption device can activate. The absorption device has a trigger, or threshold voltage, that is above the normal operating voltage of the OPA1688 but below the device breakdown voltage level. When this threshold is exceeded, the absorption device quickly activates and clamps the voltage across the supply rails to a safe level.

When the operational amplifier connects into a circuit (Figure 8-5), the ESD protection components are intended to remain inactive and do not become involved in the application circuit operation. However, circumstances may arise where an applied voltage exceeds the operating voltage range of a given pin. If this condition occurs, there is a risk that some internal ESD protection circuits can turn on and conduct current. Any such current flow occurs through steering-diode paths and rarely involves the absorption device.

Figure 8-5 shows a specific example where the input voltage (V_{IN}) exceeds the positive supply voltage ($+V_S$) by 500 mV or more. Much of what happens in the circuit depends on the supply characteristics. If $+V_S$ can sink the current, one of the upper input steering diodes conducts and directs current to $+V_S$. Excessively high current levels can flow with increasingly higher V_{IN} . As a result, the data sheet specifications recommend that applications limit the input current to 10 mA.

If the supply is not capable of sinking the current, V_{IN} can begin sourcing current to the operational amplifier and then take over as the source of positive supply voltage. The danger in this case is that the voltage can rise to levels that exceed the operational amplifier absolute maximum ratings.



Another common question involves what happens to the amplifier if an input signal is applied to the input when the power supplies $(+V_S \text{ or } -V_S)$ are at 0 V. Again, this question depends on the supply characteristic when at 0 V, or at a level below the input-signal amplitude. If the supplies appear as high impedance, then the input source supplies the operational amplifier current through the current-steering diodes. This state is not a normal bias condition; most likely, the amplifier will not operate normally. If the supplies are low impedance, then the current through the steering diodes can become quite high. The current level depends on the ability of the input source to deliver current, and any resistance in the input path.

If there is any uncertainty about the ability of the supply to absorb this current, add external zener diodes to the supply pins; see Figure 8-5. Select the zener voltage so that the diode does not turn on during normal operation. However, the zener voltage must be low enough so that the zener diode conducts if the supply pin begins to rise above the safe-operating, supply-voltage level.

The OPA1688 input pins are protected from excessive differential voltage with back-to-back diodes; see Figure 8-5. In most circuit applications, the input protection circuitry has no effect. However, in low-gain or G = 1 circuits, fast-ramping input signals can forward-bias these diodes because the output of the amplifier cannot respond rapidly enough to the input ramp. If the input signal is fast enough to create this forward-bias condition, limit the input signal current to 10 mA or less. If the input signal current is not inherently limited, an input series resistor can be used to limit the input signal current. This input series resistor degrades the low-noise performance of the OPA1688. Figure 8-5 illustrates an example configuration that implements a current-limiting feedback resistor.

8.4.3 Overload Recovery

Overload recovery is defined as the time required for the op amp output to recover from the saturated state to the linear state. The output devices of the op amp enter the saturation region when the output voltage exceeds the rated operating voltage, either resulting from the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices need time to return back to the normal state. After the charge carriers return back to the equilibrium state, the device begins to slew at the normal slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time. The overload recovery time for the OPA1688 is approximately 200 ns.



9 Applications and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The OPA1688 is specified for operation from 4.5 V to 36 V (± 2.25 V to ± 18 V). Many of the specifications apply from -40° C to $+85^{\circ}$ C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in the *Typical Characteristics*.

9.2 Typical Application

9.2.1 Headphone Amplifier Circuit Configuration

This application example highlights only a few of the circuits where the OPA1688 can be used.

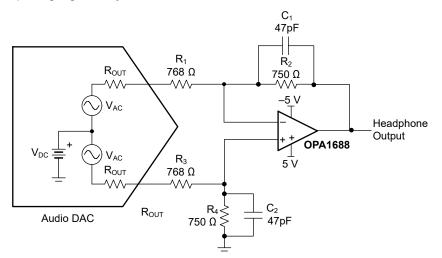


Figure 9-1. Headphone Amplifier Circuit Configuration for Audio DACs that Output a Differential Voltage (Single Channel Shown)

9.2.1.1 Design Requirements

The design requirements are:

- Supply voltage: 10 V (±5 V)
- Headphone loads: 16 Ω to 600 Ω
- THD+N: > 100 dB (1-kHz fundamental, 1 V_{RMS} in 32 Ω, 22.4-kHz measurement bandwidth)
- Output power (before clipping): 50 mW into 32 Ω



9.2.1.2 Detailed Design Procedure

The OPA1688 offers an excellent combination of specifications for headphone amplifier circuits (such as low noise, low distortion, capacitive load stability, and relatively high output current). Furthermore, the low-power supply current and small package options make the OPA1688 an excellent choice for headphone amplifiers in portable devices. A common headphone amplifier circuit for audio digital-to-analog converters (DACs) with differential voltage outputs is illustrated in Figure 9-1. This circuit converts the differential voltage output of the DAC to a single-ended, ground-referenced signal and provides the additional current necessary for low-impedance headphones. For $R_2 = R_4$ and $R_1 = R_3$, the output voltage of the circuit is given by Equation 1:

$$V_{OUT} = 2 \times V_{AC} \frac{R_2}{R_1 + R_{OUT}}$$
(1)

where

- R_{OUT} is the output impedance of the DAC
- 2 × V_{AC} is the unloaded differential output voltage

The output voltage required for headphones depends on the headphone impedance as well as the headphone efficiency. Both values can be provided by the headphone manufacturer, with headphone efficiency usually given as a sound pressure level (SPL) produced with 1 mW of input power and denoted by the Greek letter η . The SPL at other input power levels can be calculated from the efficiency specification using Equation 2:

SPL (dB) =
$$\eta$$
 + 10 log $\left(\frac{P_{IN}}{1 \text{ mW}}\right)$ (2)

At extremely high power levels, the accuracy of this calculation decreases as a result of secondary effects in the headphone drivers. Figure 9-2 allows the SPL produced by a pair of headphones of a known sensitivity to be estimated for a given input power.

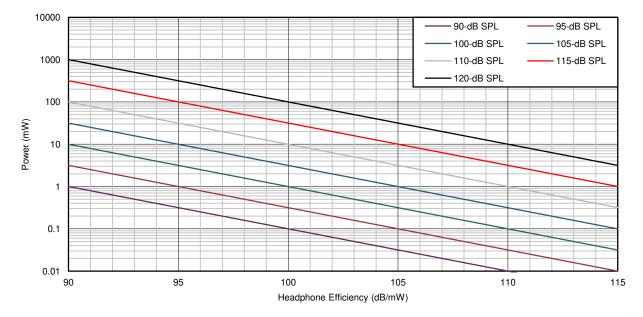


Figure 9-2. SPLs Produced for Various Headphone Efficiencies and Input Power Levels



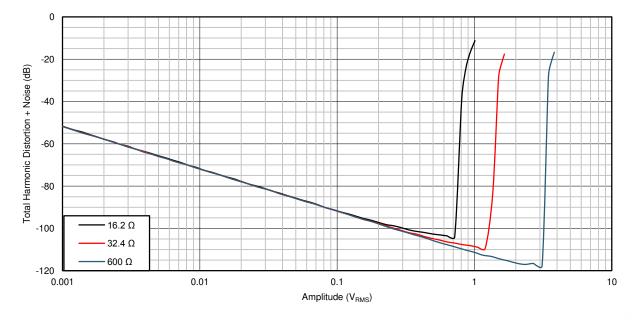
For example, a pair of headphones with a 95-dB/mW sensitivity given a 3-mW input signal produces a 100-dB SPL. If these headphones have a nominal impedance of 32 Ω , then Equation 3 and Equation 4 describe the voltage and current from the headphone amplifier, respectively:

$$V = \sqrt{P_{IN} \times R_{HP}} = \sqrt{3 \text{ mW} \times 32 \Omega} = 310 \text{ mV}_{RMS}$$
(3)
$$I = \sqrt{\frac{P_{IN}}{R_{HP}}} = \sqrt{\frac{3 \text{ mW}}{32 \Omega}} = 9.68 \text{ mA}_{RMS}$$
(4)

Headphones can present a capacitive load at high frequencies that can destabilize the headphone amplifier circuit. Many headphone amplifiers use a resistor in series with the output to maintain stability; however this solution also compromises audio quality. The OPA1688 is able to maintain stability into large capacitive loads; therefore, a series output resistor is not necessary in the headphone amplifier circuit. TINA-TI™ simulations illustrate that the circuit in Figure 9-1 has a phase margin of approximately 50° with a 400-pF load connected directly to the amplifier output.

9.2.1.3 Application Curves

The headphone amplifier circuit in Figure 9-1 is tested with three common headphone impedances: 16 Ω , 32 Ω , and 600 Ω . The total harmonic distortion and noise (THD+N) for increasing output voltages is given in Figure 9-3. This measurement is performed with a 1-kHz input signal and a measurement bandwidth of 22.4 kHz. The maximum output power and THD+N before clipping are given in Table 9-1. The maximum output power into low-impedance headphones is limited by the output current capabilities of the amplifier. For high-impedance headphones (600 Ω), the output voltage capabilities of the amplifier are the limiting factor. The circuit in Figure 9-1 is tested using ±5-V supplies that are common in many portable systems. However, using higher supply voltages increases the output power into 600- Ω headphones.



Input signal = 1 kHz, measurement bandwidth = 22.4 kHz

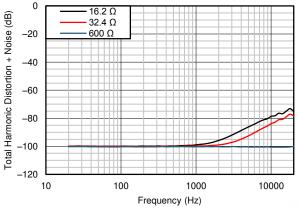
Figure 9-3. THD+N for Increasing Output Voltages Into Three Load Impedances

Table o 1. Maximum Output i ower and The in Berore onpping for Emerent Load impedances										
LOAD IMPEDANCE (Ω)	MAXIMUM OUTPUT POWER BEFORE CLIPPING (mW)	THD+N AT MAXIMUM OUTPUT POWER (dB)								
16	32	-104.1								
32	50	-109.5								
600	16	-117.8								

Table 9-1. Maximum Output Power and THD+N Before Clipping for Different Load Impedances

Figure 9-4, Figure 9-5, and Figure 9-6 further illustrate the exceptional performance of the OPA1688 as a headphone amplifier.

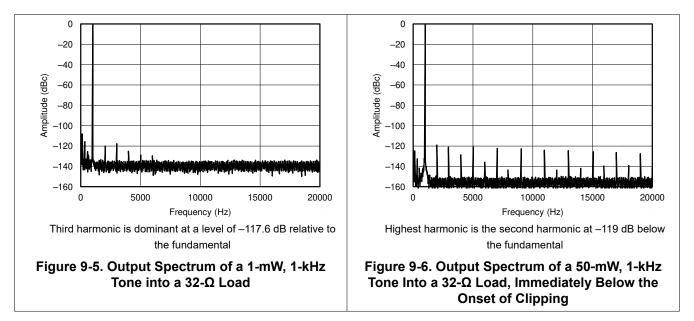
Figure 9-4 shows the THD+N over frequency for a 500-mV_{RMS} output signal into the same three load impedances previously tested.



90-kHz measurement bandwidth

Figure 9-4. THD+N Measured over Frequency for a 500-mV_{RMS} Output Level

Figure 9-5 and Figure 9-6 show the output spectrum of the OPA1688 at low (1 mW) and high (50 mW) output power levels into a $32-\Omega$ load. The distortion harmonics in both cases are approximately 120 dB below the fundamental.





10 Power Supply Recommendations

The OPA1688 is specified for operation from 4.5 V to 36 V (± 2.25 V to ± 18 V); many specifications apply from -40° C to $+85^{\circ}$ C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in *Section 7.6*.

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see also Section 7.1.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see also *Section 11*.

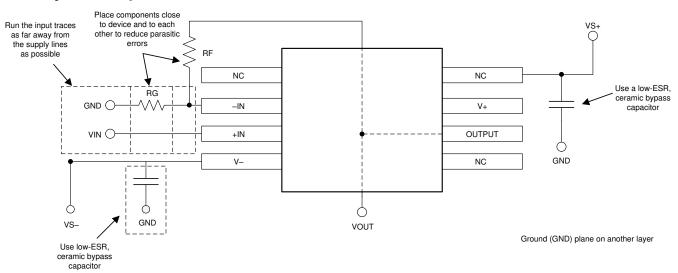


11 Layout

11.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the op amp itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as
 possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicularly is much better
 than in parallel with the noisy trace.
- Place the external components as close to the device as possible. Figure 11-1 illustrates how keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.



11.2 Layout Example

Figure 11-1. Operational Amplifier Board Layout for a Noninverting Configuration



12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 PSpice[®] for TI

PSpice[®] for TI is a design and simulation environment that helps evaluate performance of analog circuits. Create subsystem designs and prototype solutions before committing to layout and fabrication, reducing development cost and time to market.

12.1.1.2 TINA-TI™ Simulation Software (Free Download)

TINA-TI[™] simulation software is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI simulation software is a free, fully-functional version of the TINA[™] software, preloaded with a library of macromodels, in addition to a range of both passive and active models. TINA-TI simulation software provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Design tools and simulation web page, TINA-TI simulation software offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

Note

These files require that either the TINA software or TINA-TI software be installed. Download the free TINA-TI simulation software from the TINA-TI™ software folder.

12.2 Documentation Support

12.2.1 Related Documentation

- Texas Instruments, Feedback Plots Define Op Amp AC Performance application note
- Texas Instruments, EMI Rejection Ratio of Operational Amplifiers application note
- Texas Instruments, *Op Amps for Everyone* application note
- Texas Instruments, Capacitive Load Drive Solution Using an Isolation Resistor reference design

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
OPA1688ID	ACTIVE	SOIC	D	0	75	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	40 to 95	O1688A	_
OPAT688ID	ACTIVE	5010	D	o	75	RUNS & Green	NIPDAU	Level-2-200C-1 TEAR	-40 to 85	01666A	Samples
OPA1688IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	O1688A	Samplas
											Samples
OPA1688IDRGR	ACTIVE	SON	DRG	8	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OP1688	Samples
											1
OPA1688IDRGT	ACTIVE	SON	DRG	8	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OP1688	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA1688IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA1688IDRGR	SON	DRG	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
OPA1688IDRGT	SON	DRG	8	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2



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PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA1688IDR	SOIC	D	8	2500	356.0	356.0	35.0
OPA1688IDRGR	SON	DRG	8	3000	367.0	367.0	35.0
OPA1688IDRGT	SON	DRG	8	250	210.0	185.0	35.0

TEXAS INSTRUMENTS

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3-Jun-2022

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
OPA1688ID	D	SOIC	8	75	506.6	8	3940	4.32

D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA



E. JEDEC MO-229 package registration pending.



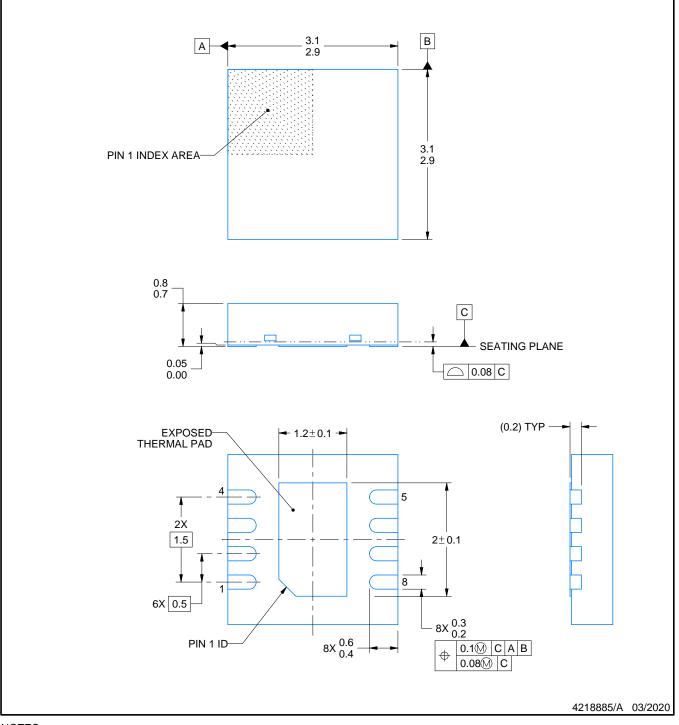
DRG0008A



PACKAGE OUTLINE

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

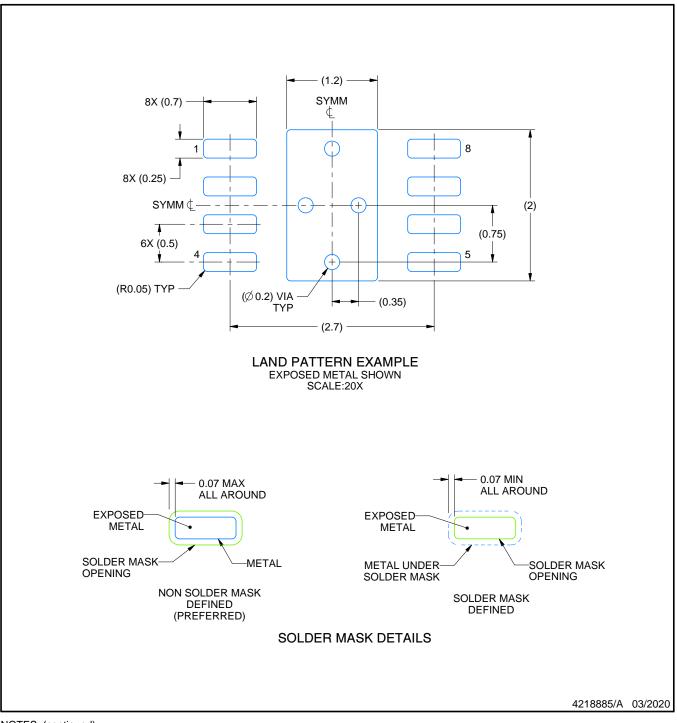


DRG0008A

EXAMPLE BOARD LAYOUT

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

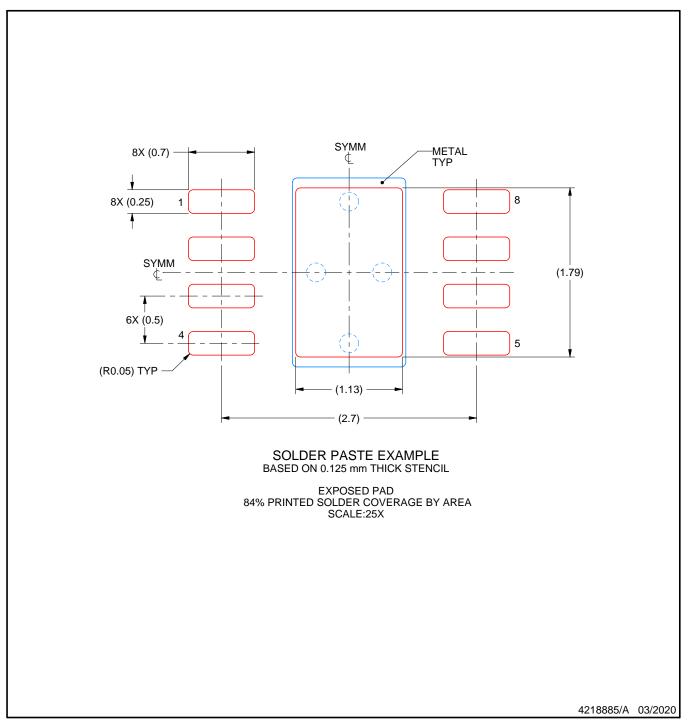


DRG0008A

EXAMPLE STENCIL DESIGN

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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